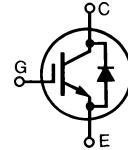


HiPerFAST™ IGBT with Diode

Short Circuit SOA Capability

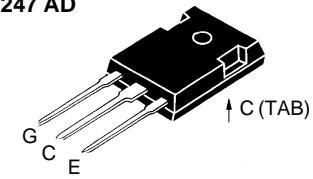
IXSH 24N60U1
IXSH24N60AU1

V_{CES}	I_{C25}	V_{CE(sat)}
600 V	48 A	2.2 V
600 V	48 A	2.7 V



Symbol	Test Conditions	Maximum Ratings		
V_{CES}	T _j = 25°C to 150°C	600	V	
V_{CGR}	T _j = 25°C to 150°C; R _{GE} = 1 MΩ	600	V	
V_{GES}	Continuous	±20	V	
V_{GEM}	Transient	±30	V	
I_{C25}	T _c = 25°C	48	A	
I_{C90}	T _c = 90°C	24	A	
I_{CM}	T _c = 25°C, 1 ms	96	A	
SSOA (RBSOA)	V _{GE} = 15 V, T _{vJ} = 125°C, R _G = 10 Ω Clamped inductive load, L = 100 μH	I _{CM} = 48 @ 0.8 V _{CES}	A	
t_{sc} (SCSOA)	V _{GE} = 15 V, V _{CE} = 360 V, T _j = 125°C, R _G = 82 Ω, non-repetitive	10	μs	
P_c	T _c = 25°C	150	W	
T_j		-55 ... +150	°C	
T_{JM}		150	°C	
T_{stg}		-55 ... +150	°C	
Maximum Lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	°C	
Maximum Tab temperature for soldering SMD devices for 10 s		260	°C	
M_d	Mounting torque, TO-247	1.13/10	Nm/lb.in.	
Weight	TO-247 AD	6	g	

TO-247 AD



G = Gate,
E = Emitter,
C = Collector,
TAB = Collector

Features

- International standard package JEDEC TO-247 AD
- High frequency IGBT and anti-parallel FRED in one package
- 2nd generation HDMOS™ process
- Low V_{CE(sat)}
 - for minimum on-state conduction losses
- MOS Gate turn-on
 - drive simplicity
- Fast Recovery Epitaxial Diode (FRED)
 - soft recovery with low I_{RM}

Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

Advantages

- Space savings (two devices in one package)
- Suitable for surface mounting
- Easy to mount with 1 screw, TO-247 (isolated mounting screw hole)
- Reduces assembly time and cost

Symbol	Test Conditions	Characteristic Values		
		(T _j = 25°C, unless otherwise specified)		
		min.	typ.	max.
BV_{CES}	I _C = 750 μA, V _{GE} = 0 V	600		V
V_{GE(th)}	I _C = 1.5 mA, V _{CE} = V _{GE}	3.5		V
I_{CES}	V _{CE} = 0.8 • V _{CES} V _{GE} = 0 V	T _j = 25°C T _j = 125°C	500 8	μA mA
I_{GES}	V _{CE} = 0 V, V _{GE} = ±20 V		±100	nA
V_{CE(sat)}	I _C = I _{C90} , V _{GE} = 15 V	IXSH 24N60U1 IXSH 24N60AU1	2.2 2.7	V

IXYS reserves the right to change limits, test conditions, and dimensions.

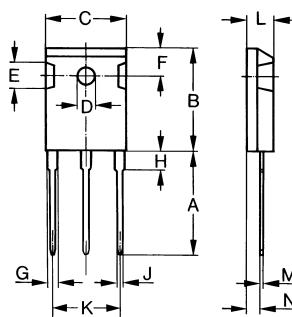
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Symbol	Test Conditions	Characteristic Values		
		(T _J = 25°C, unless otherwise specified)		
		min.	typ.	max.
g_{fs}	$I_c = I_{C90}$; $V_{CE} = 10$ V, Pulse test, $t \leq 300$ μ s, duty cycle ≤ 2 %	9	13	S
$I_{c(on)}$	$V_{GE} = 15$ V, $V_{CE} = 10$ V	65		A
C_{ies} C_{oes} C_{res}	$V_{CE} = 25$ V, $V_{GE} = 0$ V, $f = 1$ MHz	1800 200 45		pF pF pF
Q_g Q_{ge} Q_{gc}	$I_c = I_{C90}$, $V_{GE} = 15$ V, $V_{CE} = 0.5 V_{CES}$	75 20 35	90 30 50	nC nC nC
$t_{d(on)}$ t_{ri} $t_{d(off)}$ t_{fi}	Inductive load, $T_J = 25^\circ\text{C}$ $I_c = I_{C90}$, $V_{GE} = 15$ V, $L = 100$ μ H, $V_{CE} = 0.8 V_{CES}$, $R_G = R_{off} = 10 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_J or increased R_G	100 200 450 500		ns ns ns ns
E_{off}	24N60U1 24N60AU1 24N60AU1	275 2		ns mJ
$t_{d(on)}$ t_{ri} E_{on} $t_{d(off)}$ t_{fi}	Inductive load, $T_J = 125^\circ\text{C}$ $I_c = I_{C90}$, $V_{GE} = 15$ V, $L = 100$ μ H $V_{CE} = 0.8 V_{CES}$, $R_G = R_{off} = 10 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_J or increased R_G	100 200 1.8 475 600 450		ns ns mJ ns ns ns
E_{off}	24N60U1 24N60AU1	4 3		mJ mJ
R_{thJC}				0.83 K/W
R_{thCK}		0.25		K/W

TO-247 AD (IXSH) Outline



Dim.	Millimeter Min. Max.	Inches Min. Max.
A	19.81 20.32	0.780 0.800
B	20.80 21.46	0.819 0.845
C	15.75 16.26	0.610 0.640
D	3.55 3.65	0.140 0.144
E	4.32 5.49	0.170 0.216
F	5.4 6.2	0.212 0.244
G	1.65 2.13	0.065 0.084
H	- 4.5	- 0.177
J	1.0 1.4	0.040 0.055
K	10.8 11.0	0.426 0.433
L	4.7 5.3	0.185 0.209
M	0.4 0.8	0.016 0.031
N	1.5 2.49	0.087 0.102

Reverse Diode (FRED)

Characteristic Values

(T_J = 25°C, unless otherwise specified)

Symbol	Test Conditions	min.	typ.	max.
V_F	$I_F = I_{C90}$, $V_{GE} = 0$ V, Pulse test, $t \leq 300$ μ s, duty cycle $d \leq 2$ %		1.6	V
t_{RM} t_{rr}	$I_F = I_{C90}$, $V_{GE} = 0$ V, $-di_F/dt = 240$ A/ μ s $V_R = 360$ V $I_F = 1$ A; $-di/dt = 100$ A/ μ s; $V_R = 30$ V $T_J = 125^\circ\text{C}$ $I_F = 1$ A; $-di/dt = 100$ A/ μ s; $V_R = 30$ V $T_J = 25^\circ\text{C}$	10 150 35	15 ns 50	A ns ns
R_{thJC}			1	K/W